

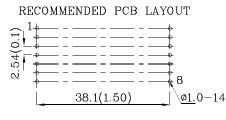
## Part Number: XMMDK50A

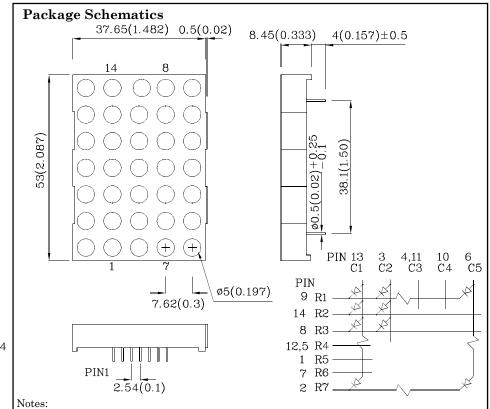
50mm (2.0 ") 5x7 DOT MATRIX DISPLAY

### Features

- $\bullet$  Low power consumption
- $\bullet$  Robust package
- I.C. Compatible
- Standard configuration: Gray face w/ white dots
- Optional black face provides superior color contrast
- RoHS Compliant







All dimensions are in millimeters (inches), Tolerance is ±0.25(0.01")unless otherwise noted.
Specifications are subject to change without notice.

Absolute Maximum Ratings (T <sub>A</sub> =25°C)		MDK (AlGaInP)	Unit	
Reverse Voltage	$V_{R}$	5	V	
Forward Current	$I_{\rm F}$	30	mA	
Forward Current (Peak) 1/10 Duty Cycle 0.1ms Pulse Width	ifs	185	mA	
Power Dissipation	$P_{D}$	75	mW	
Operating Temperature	$T_{\rm A}$	$-40 \sim +85$	°C	
Storage Temperature	Tstg	$-40 \sim +85$	U	
Lead Solder Temperature [2mm Below Package Base]	260°C For 3-5 Seconds			

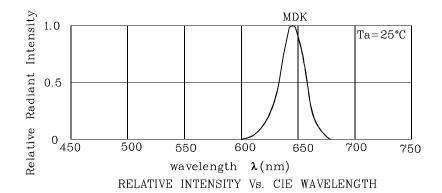
Operating Characteristics (T <sub>A</sub> =25°C)		MDK (AlGaInP)	Unit
Forward Voltage (Typ.) (I <sub>F</sub> =10mA)	V <sub>F</sub> 1.85		V
Forward Voltage (Max.) (I <sub>F</sub> =10mA)	$V_{\mathrm{F}}$	2.5	V
Reverse Current (Max.) (V <sub>R</sub> =5V)	$I_R$	10	uA
Wavelength of Peak Emission CIE127-2007* (Typ.) (I <sub>F</sub> =10mA)	λP	λP 645*	
Wavelength of Dominant Emission CIE127-2007* (Typ.) (I <sub>F</sub> =10mA)	λD	630*	nm
Spectral Line Full Width At Half-Maximum (Typ.) (I <sub>F</sub> =10mA)	$ riangle \lambda$	28	nm
Capacitance (Typ.) (V <sub>F</sub> =0V, f=1MHz)	С	35	pF

Part Number	Emitting Color	Emitting Material	Luminous Intensity CIE127-2007* (I <sub>F</sub> =10mA) ucd		Wavelength CIE127-2007* nm λP	Description
			min.	typ.		
XMMDK50A	Red	AlGaInP	52000 21000*	129990 41990*	645*	Column Anode

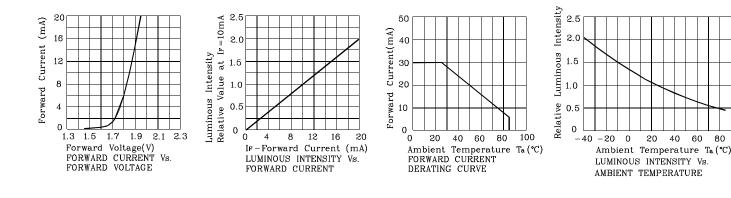
\*Luminous intensity value and wavelength are in accordance with CIE127-2007 Mar 04,2014

XDSA8570 V2-X Layout: Maggie L.

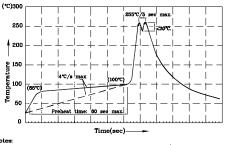




### MDK



Wave Soldering Profile for Thru-Hole Products (Pb-Free Components)



Access I.Recommend pre-heat temperature of 105°C or less (as measured with a thermocouple attached to the LED pins) prior to immersion in the solder wave with a maximum solder bath temperature of 260°C 2.Peak wave soldering temperature between 245°C ~ 255°C for 3 sec (5 sec max)

Peak wave soldering temperature between 2+30 - 2+30

#### Remarks:

If special sorting is required (e.g. binning based on forward voltage,

luminous intensity / luminous flux, or wavelength),

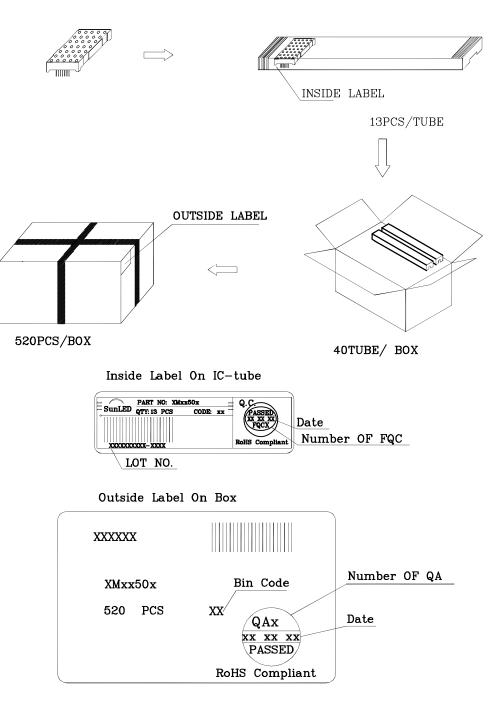
the typical accuracy of the sorting process is as follows:

- 1. Wavelength: +/-1nm
- 2. Luminous Intensity / Luminous Flux: +/-15%
- 3. Forward Voltage: +/-0.1V
- Note: Accuracy may depend on the sorting parameters.

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# **PACKING & LABEL SPECIFICATIONS**



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- 2. Contents within this document are subject to improvement and enhancement changes without notice.
- 3. The product(s) in this document are designed to be operated within the electrical and environmental specifications indicated on the datasheet.
- User accepts full risk and responsibility when operating the product(s) beyond their intended specifications.
- 4. The product(s) described in this document are intended for electronic applications in which a person's life is not reliant upon the LED. Please
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- $6. \ Additional \ technical \ notes \ are \ available \ at \ \underline{http://www.SunLEDusa.com/TechnicalNotes.asp}$